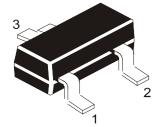
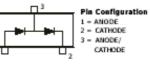
## LOW LEAKAGE DUAL SWITCHING DIODE







**BAV199** 

SOT-23 Formed SMD Package

Series Pair Configuration Marking Code : PX

### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C unless otherwise specified)

DESCRIPTION		SYMBOL	VALUE	UNITS	
Repetitive Peak Reverse Voltage		V <sub>RRM</sub>	85	V	
Continuous Reverse Voltage		V <sub>R</sub>	85	V	
Forward Continuous Current	Single Diode	I <sub>F</sub> -	160	mA	
	Double Diode		140		
Repetitive Peak Forward Current		I <sub>FRM</sub>	500	mA	
Non-Repetitive Peak Forward Surge Current					
	@ t = 1 μs	I	4	Α	
@ t = 1 ms		I <sub>FSM</sub>	1	A	
	@ t = 1 s		0.5		
Power Dissipation		P <sub>D</sub>	250	mW	
Thermal Resistance Junction to Ambient Air		$R_{ ext{ heta}JA}$	500	°C/W	
Operating and Storage Temperature Range		$T_{j,}T_{STG}$	-65 to +150	°C	

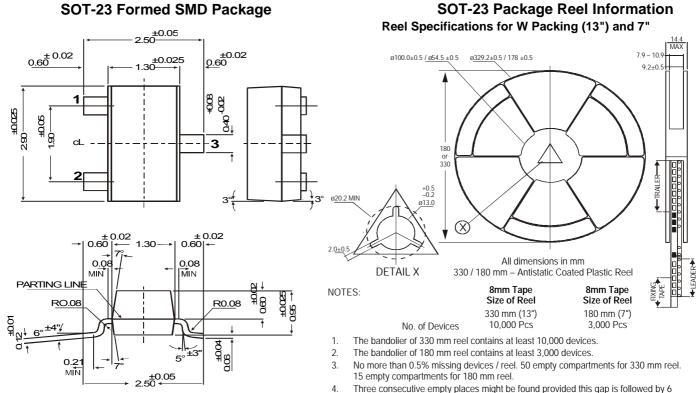
### Electrical Characterstics (T<sub>a</sub>=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	CONDITIONS	MIN	MAX	UNIT
Reverse Breakdown Voltage	V <sub>(BR)R</sub>	I <sub>R</sub> =100μΑ	85		V
		I <sub>F</sub> =1mA		0.9	- V
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =10mA		1.0	
Forward Voltage		I <sub>F</sub> =50mA		1.1	
		I <sub>F</sub> =150mA		1.25	
	I <sub>R</sub>	V <sub>R</sub> =75V		5	nA
Reverse Current		V <sub>R</sub> =75V, T <sub>j</sub> =150°C		80	
Total Capacitance	C <sub>T</sub>	V <sub>R</sub> =0, f=1MHz	Ту	p 2	рF
Reverse Recovery Time	t <sub>rr</sub>	$I_F=I_R=10mA$ , Irr=0.1XI <sub>R</sub> , R <sub>L</sub> =100 $\Omega$		3	us

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4. Three consecutive empty places might be found provided this gap is followed by 6 consecutive devices.

 The carrier tape (leader) starts with at least 75 empty positions (equivalent to 330 mm). In order to fix the carrier tape a self adhesive tape of 20 to 50 mm is applied. At the end of the bandolier at least 40 empty positions (equivalent to 160 mm) are there.

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**Customer Notes** 



**BAV199** 

#### Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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